

**MSASC100W45H**  
**MSASC100W45HR**  
 Or  
**1N6791**

**45 Volts**  
**100 Amps**

**SURFACE MOUNT**  
**LOW LEAKAGE**  
**SCHOTTKY DIODE**

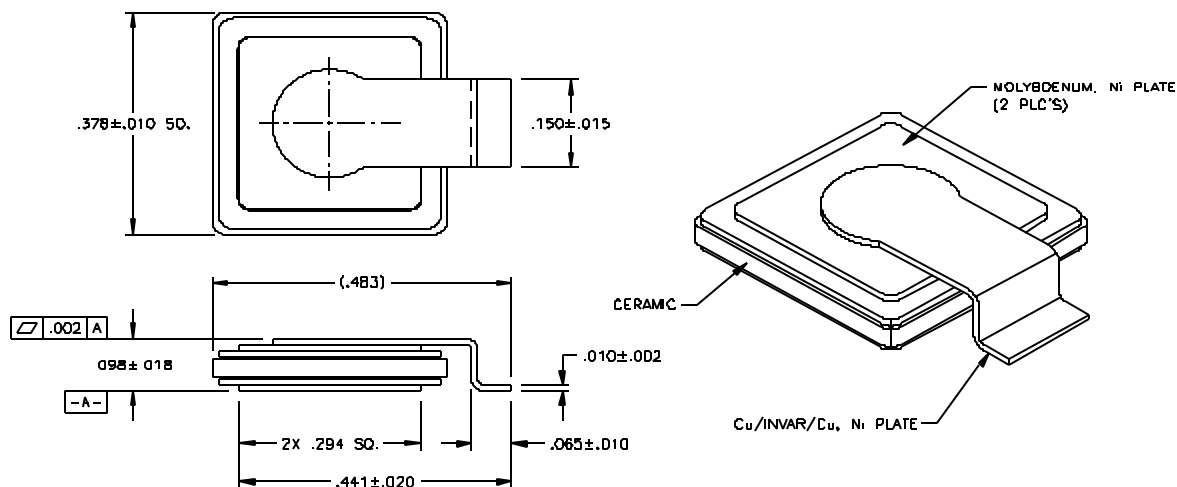
## Features

- Tungsten schottky barrier
- Oxide passivated structure for very low leakage currents
- Guard ring protection for increased reverse energy capability
- Epitaxial structure minimizes forward voltage drop
- Hermetically sealed, low profile ceramic surface mount power package
- Low package inductance
- Very low thermal resistance
- Available as standard polarity (strap-to-anode, MSASC100W45H) and reverse polarity (strap-to-cathode: MSASC100W45HR)

## Maximum Ratings @ 25 °C (unless otherwise specified)

| DESCRIPTION                                                                     | SYMBOL        | MAX.                          | UNIT                   |
|---------------------------------------------------------------------------------|---------------|-------------------------------|------------------------|
| Peak Repetitive Reverse Voltage                                                 | $V_{RRM}$     | 45                            | Volts                  |
| Working Peak Reverse Voltage                                                    | $V_{RWM}$     | 45                            | Volts                  |
| DC Blocking Voltage                                                             | $V_R$         | 45                            | Volts                  |
| Average Rectified Forward Current, $T_c \leq 145^\circ\text{C}$                 | $I_{F(ave)}$  | 100                           | Amps                   |
| derating, forward current, $T_c \geq 145^\circ\text{C}$                         | $dl_F/dT$     | 3.3                           | Amps/ $^\circ\text{C}$ |
| Nonrepetitive Peak Surge Current, $t_p = 8.3$ ms, half-sinewave                 | $I_{FSM}$     | 500                           | Amps                   |
| Peak Repetitive Reverse Surge Current, $t_p = 1\mu\text{s}$ , $f = 1\text{kHz}$ | $I_{RRM}$     | 2                             | Amp                    |
| Junction Temperature Range                                                      | $T_j$         | -65 to +175                   | $^\circ\text{C}$       |
| Storage Temperature Range                                                       | $T_{stg}$     | -65 to +175                   | $^\circ\text{C}$       |
| Thermal Resistance, Junction to Case:                                           | $\theta_{JC}$ | 0.35<br>0.5                   | $^\circ\text{C/W}$     |
|                                                                                 |               | MSASC100W45H<br>MSASC100W45HR |                        |

## Mechanical



## Electrical Parameters

| DESCRIPTION                                                                 | SYMBOL        | CONDITIONS                                         | MIN | TYP. | MAX  | UNIT |
|-----------------------------------------------------------------------------|---------------|----------------------------------------------------|-----|------|------|------|
| Reverse (Leakage) Current                                                   | $I_{R_{25}}$  | $V_R = 45 \text{ Vdc}$ , $T_c = 25^\circ\text{C}$  |     | .01  | 1    | mA   |
|                                                                             | $I_{R_{125}}$ | $V_R = 45 \text{ Vdc}$ , $T_c = 125^\circ\text{C}$ |     | 10   | 100  | mA   |
| Forward Voltage<br>pulse test,<br>$p_w = 300 \mu\text{s}$<br>$d/c \leq 2\%$ | VF1           | $I_F = 10\text{A}$ , $T_c = 25^\circ\text{C}$      |     | 500  | 550  | mV   |
|                                                                             | VF2           | $I_F = 20\text{A}$ , $T_c = 25^\circ\text{C}$      |     | 560  | 600  | mV   |
|                                                                             | VF3           | $I_F = 40\text{A}$ , $T_c = 25^\circ\text{C}$      |     | 610  | 675  | mV   |
|                                                                             | VF4           | $I_F = 80\text{A}$ , $T_c = 25^\circ\text{C}$      |     | 740  | 800  | mV   |
|                                                                             | VF5           | $I_F = 100\text{A}$ , $T_c = 25^\circ\text{C}$     |     | 800  |      | mV   |
|                                                                             | VF6           | $I_F = 20\text{A}$ , $T_c = -55^\circ\text{C}$     |     | 650  | 700  | mV   |
|                                                                             | VF7           | $I_F = 20\text{A}$ , $T_c = 125^\circ\text{C}$     |     | 450  |      | mV   |
| Junction Capacitance                                                        | Cj1           | $V_R = 10 \text{ Vdc}$                             |     | 2500 | 3000 | pF   |
|                                                                             | Cj2           | $V_R = 5 \text{ Vdc}$                              |     | 3500 |      | pF   |
| Breakdown Voltage                                                           | BVR           | $I_R = 5 \text{ mA}$ , $T_c = 25^\circ\text{C}$    |     | 55   |      | V    |
|                                                                             |               | $I_R = 5 \text{ mA}$ , $T_c = -55^\circ\text{C}$   | 45  | 50   |      | V    |

VF vs IF Typical Curves

